

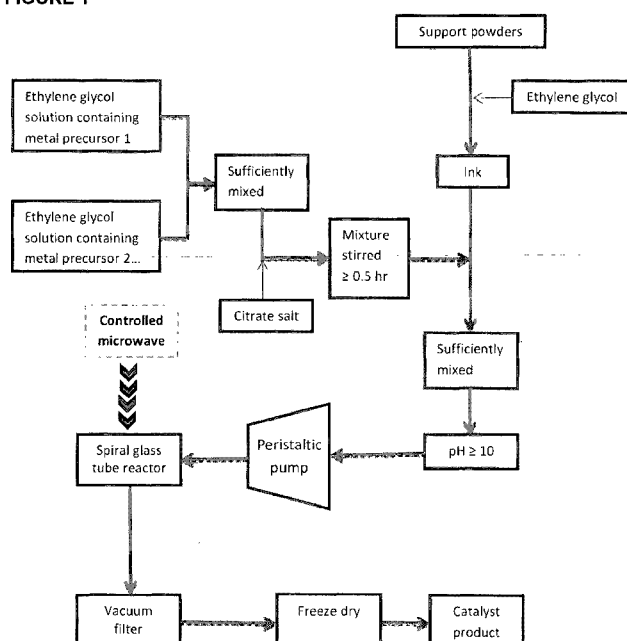


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[Continued on next page]

(54) **Title:** METHOD FOR FORMING NOBLE METAL NANOPARTICLES ON A SUPPORT

FIGURE 1



(57) **Abstract:** The invention relates to a method for forming noble metal nanoparticles on a support. In particular, the method includes heating precursors of the noble metal nanoparticles in a spiral glass tube reactor to reduce the precursors to form the noble metal nanoparticles on the support.



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